NSN 5962-01-555-7524

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-555-7524

Overal	I Length:

Between 1.170 inches and 1.230 inches

Overall Height:

Between 0.255 inches and 0.370 inches

Overall Width:

Between 0.310 inches and 0.385 inches

Body Length:

Between 1.170 inches and 1.230 inches

Body Width:

Between 0.250 inches and 0.270 inches

Body Height:

Between 0.120 inches and 0.140 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0 to 125.0 degrees celsius

Storage Tempurature Range:

-65.0 to 150.0 degrees celsius

End Application:

1430-01-448-9835 communication relay group guided missile

Features Provided:

Monolithic and w/clock and w/clear and edge triggered

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Product Name:

Microcircuit, memory, digital, cmos, 512 x 8 registered programmable read only memory (prom), monolithic silicon

Voltage Rating And Type Per Characteristic:

-0.5 volts input and 7.0 volts input

Memory Device Type:

First-in first-out

Memory Capacity:

4096

Special Test Features:

80063-sm-a-915925

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

NSN 5962-01-555-7524

Memory Microcircuit - Page 2 of 2



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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0